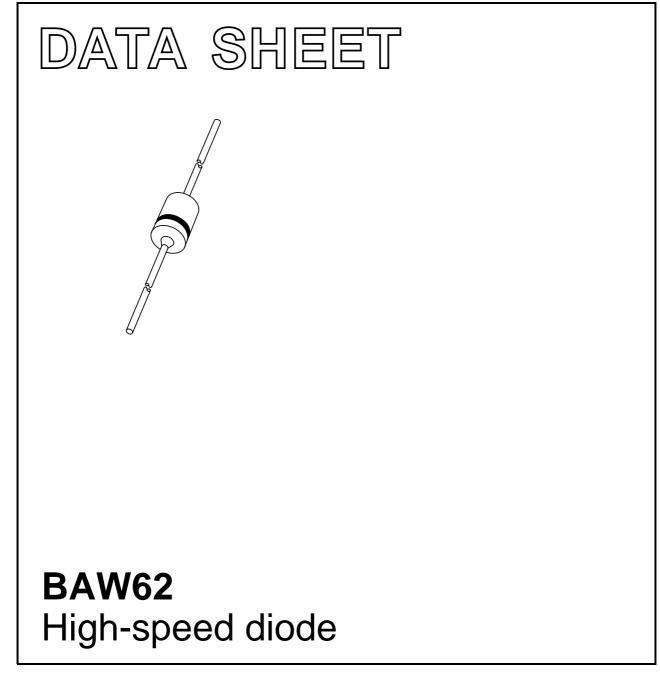
# DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of April 1996

1996 Sep 17



Product data sheet

MAM246

### BAW62

### FEATURES

- Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 75 V
- Repetitive peak forward current: max. 450 mA.

### APPLICATIONS

- High-speed switching
- Fast logic applications.

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

DESCRIPTION

 $\bigcirc$ 

The diode is type branded.

package.

The BAW62 is a high-speed switching diode fabricated in planar technology,

Fig.1 Simplified outline (SOD27; DO-35) and symbol.

and encapsulated in the hermetically sealed leaded glass SOD27 (DO-35)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage		_	75	V
V <sub>R</sub>	continuous reverse voltage		_	75	V
I <sub>F</sub>	continuous forward current	see Fig.2; note 1	_	250	mA
I <sub>FRM</sub>	repetitive peak forward current		_	450	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	4	А
		t = 1 ms	_	1	А
		t = 1 s	_	0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	_	350	mW
T <sub>stg</sub>	storage temperature		-65	+200	°C
Tj	junction temperature		_	200	°C

### Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

### BAW62

### ELECTRICAL CHARACTERISTICS

### $T_j$ = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 5 mA	620	750	mV
		I <sub>F</sub> = 100 mA	_	1000	mV
		I <sub>F</sub> = 100 mA; T <sub>j</sub> = 100 °C	_	930	mV
I <sub>R</sub>	reverse current	see Fig.5			
		V <sub>R</sub> = 20 V	_	25	nA
		V <sub>R</sub> = 50 V	-	200	nA
		V <sub>R</sub> = 75 V	_	5	μA
		V <sub>R</sub> = 20 V; T <sub>j</sub> = 150 °C	_	50	μA
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	_	100	μA
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$	_	2	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	_	4	ns
V <sub>fr</sub>	forward recovery voltage	when switched from $I_F = 50$ mA; $t_r = 20$ ns; see Fig.8	_	2.5	V

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	lead length 10 mm; note 1	500	K/W

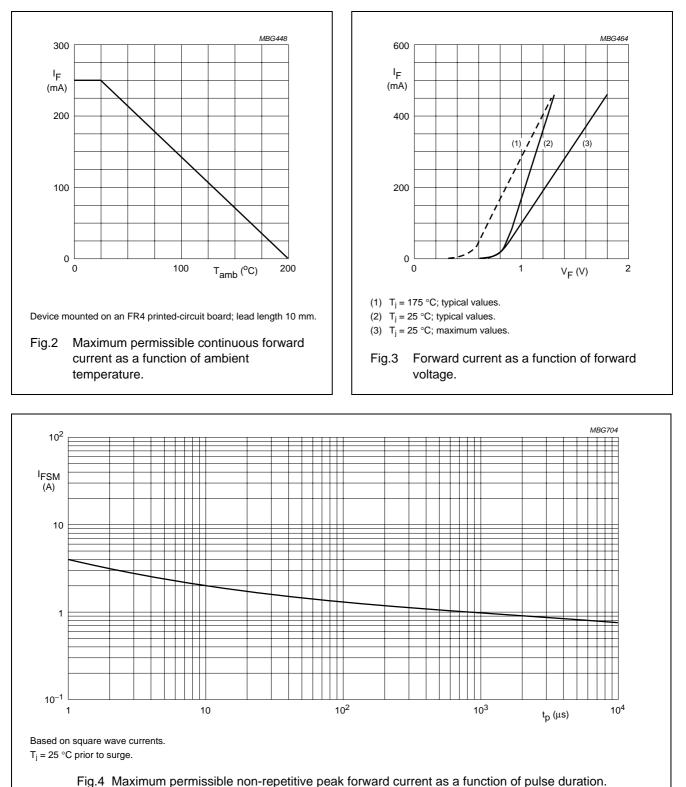
### Note

1. Device mounted on a printed circuit-board without metallization pad.

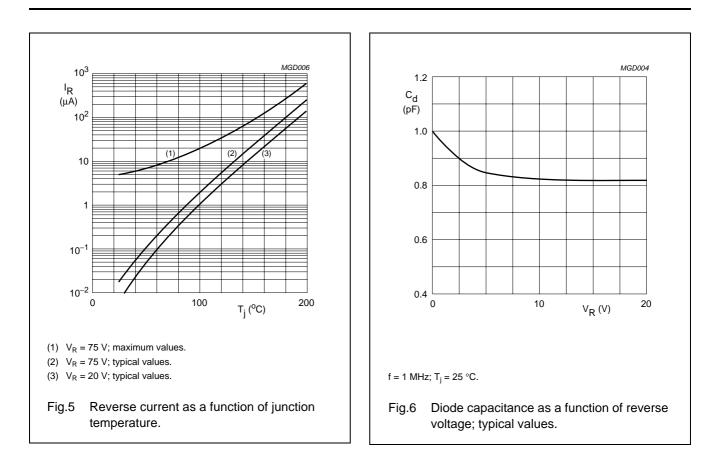
### Product data sheet

### **BAW62**

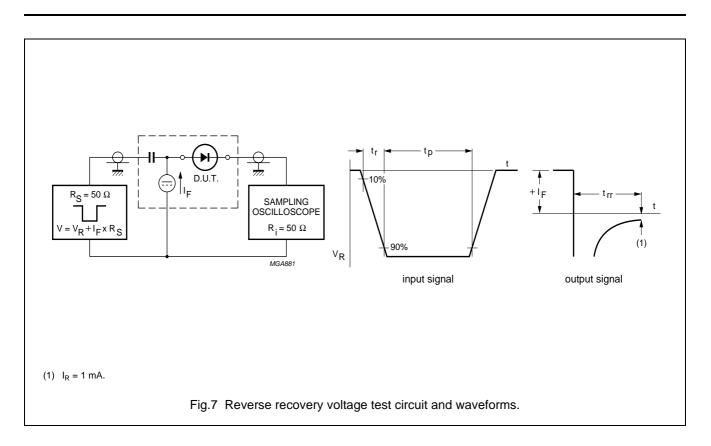
### **GRAPHICAL DATA**

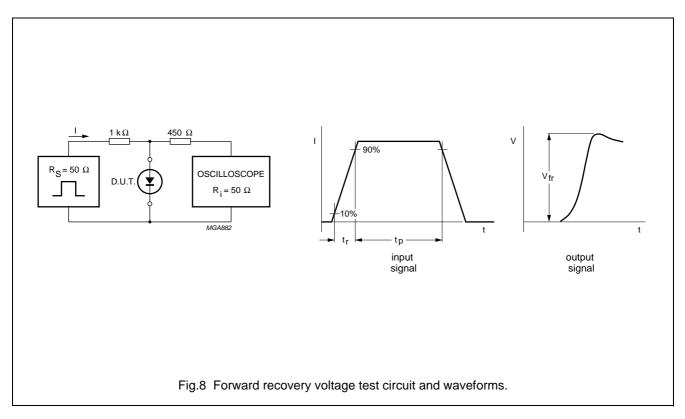


# BAW62



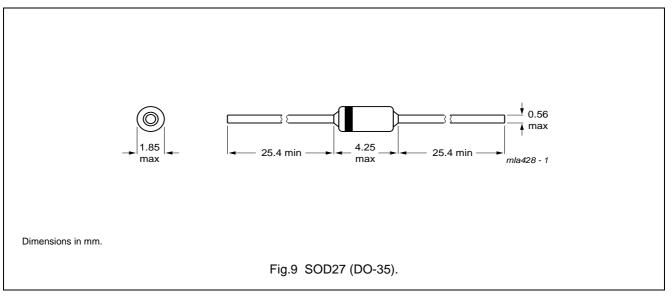
# BAW62





### BAW62

### PACKAGE OUTLINE



**BAW62** 

### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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Printed in The Netherlands

1996 Sep 17





**BAW62** 

### Products / Packages

Type number	Orderable part number	Ordering code (12NC)	Product status	Package	Packing	Marking	ECCN
BAW62	BAW62,133	9331 012 20133	Volume production	ALF2 (SOD27)	Ammo pack axial radial taped	Standard Marking	
BAW62	BAW62,113	9331 012 20113	Volume production	ALF2 (SOD27)	Reel pack axial radial	Standard Marking	
BAW62	BAW62,143	9331 012 20143	Volume production	ALF2 (SOD27)	Ammo pack axial radial taped	Standard Marking	